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July 2013

SEMICONDUCTOR FGH40T120SMD / FGH40T120SMD_F155 1200 V, 40 A FS Trench IGBT

Features

- FS Trench Technology, Positive Temperature Coefficient
- High Speed Switching

FAIRCHILD

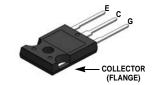
- Low Saturation Voltage: V_{CE(sat)} =1.8 V @ I_C = 40 A
- 100% of the Parts tested for I_{LM}(1)
- · High Input Impedance
- RoHS Compliant

Applications

• Solar Inverter, Welder, UPS & PFC applications.



Using innovative field stop trench IGBT technology, Fairchild®'s new series of field stop trench IGBTs offer the optimum performance for hard switching application such as solar inverter, UPS, welder and PFC applications.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		1200	V
V _{GES}	Gate to Emitter Voltage		±25	V
	Transient Gate to Emitter Voltage		±30	V
1	Collector Current	@ T _C = 25 ^o C	80	A
I _C	Collector Current	@ T _C = 100 ^o C	40	A
I _{LM} (1)	Clamped Inductive Load Current (a) $T_{C} = 25^{\circ}C$		160	А
I _{CM} (2)	Pulsed Collector Current		160	А
I _F	Diode Continuous Forward Current	@ T _C = 25 ^o C	80	A
	Diode Continuous Forward Current	@ T _C = 100 ^o C	40	А
I _{FM}	Diode Maximum Forward Current		240	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	555	W
	Maximum Power Dissipation	@ T _C = 100 ^o C	277	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second	ls	300	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case		0.27	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case		0.89	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient		40	°C/W

Notes:

1. Vcc = 600 V,V_{GE} = 15 V, I_C = 160 A, R_G = 10 \odot . Inductive Load 2. Limited by Tjmax

Device Marking		Device	Package	Reel Size	Tape Width		Quantity		
FGH40T120SMD		FGH40T120SMD	TO-247 A03	247 A03 -		-		30	
FGH40T120SMD FGH40T120SMD_F155		TO-247G03	-			30			
Electric	al Cha	racteristics of the	IGBT T _C = 25°C	unless otherwise noted					
Symbol	Symbol Parameter		Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristics								
BV _{CES}	Collector	to Emitter Breakdown Voltag	$V_{GE} = 0 V, I_C =$	250 uA	1200	-	-	V	
I _{CES}	Collector	Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$		-	-	250	uA	
I _{GES}	G-E Leak	age Current	$V_{GE} = V_{GES}, V$	_{CE} = 0 V	-	-	±400	nA	
On Charac	teristics								
V _{GE(th)}		shold Voltage	I _C = 40 mA, V _C	E = V _{GE}	4.9	6.2	7.5	V	
			$T_{\rm C} = 25^{\rm o}{\rm C}$	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V}$ $T_{C} = 25^{\circ}\text{C}$		1.8	2.4	V	
V _{CE(sat)}	Collector to Emitter Saturation Voltage		^e I _C = 40 A, V _{GE} T _C = 175°C	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 175^{\circ}\text{C}$		2.0	-	V	
Dynamic C	haracteris	stics							
C _{ies}	Input Cap	pacitance			-	4300	-	pF	
C _{oes}	Output Capacitance			V _{CE} = 30 V _, V _{GE} = 0 V, f = 1MHz	-	180	-	pF	
C _{res}	Reverse	Transfer Capacitance		1 - 110112		100	-	pF	
Switching	Characcte	ristics							
t _{d(on)}		Delay Time			-	40	-	ns	
t _r	Rise Time Turn-Off Delay Time Fall Time					47	-	ns	
t _{d(off)}			V _{CC} = 600 V, I ₀	a = 40 A	-	475	-	ns	
t _f			R _G = 10 Ω, V _G	_E = 15 V,	-	10	-	ns	
E _{on}	Turn-On	Switching Loss	Inductive Load	, T _C = 25°C	-	2.7	-	mJ	
E _{off}	Turn-Off	Switching Loss			-	1.1	-	mJ	
E _{ts}	Total Swi	tching Loss			-	3.8	-	mJ	
t _{d(on)}		Delay Time			-	40	-	ns	
t _r	Rise Time	9			-	55	-	ns	
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 600 V, I ₀	~ = 40 A,	-	520	-	ns	
t _f	Fall Time		R _G = 10 Ω, V _G	_E = 15 V,	-	50	-	ns	
E _{on}	Turn-On	Switching Loss	Inductive Load, T _C = 175°C		-	3.4	-	mJ	
E _{off}	Turn-Off	Switching Loss			-	2.5	-	mJ	
E _{ts}	Total Swi	tching Loss			-	5.9	-	mJ	
Q _g	Total Gat	e Charge			-	370	-	nC	
Q _{ge}		mitter Charge	$V_{CE} = 600 \text{ V}, \text{ I}_{CE}$	_c = 40 A,	-	23	-	nC	
Q _{gc}		collector Charge	V _{GE} = 15 V					nC	

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{FM}	Diode Forward Voltage	I _F = 40 A, T _C = 25 ^o C	-	3.8	4.8	V
		I _F = 40 A, T _C = 175°C	-	2.7	-	V
t _{rr}	Diode Reverse Recovery Time	$V_{R} = 600 \text{ V}, I_{F} = 40 \text{ A},$	-	65	-	ns
I _{rr}	Diode Peak Reverse Recovery Current	$di_F/dt = 200 A/us, T_C = 25^{\circ}C$	-	7.2	-	А
Q _{rr}	Diode Reverse Recovery Charge		-	234	-	nC
t _{rr}	Diode Reverse Recovery Time	$V_{R} = 600 \text{ V}, I_{F} = 40 \text{ A},$	-	200	-	ns
I _{rr}	Diode Peak Reverse Recovery Current	$di_{F}/dt = 200 \text{ A/us}, T_{C} = 175^{\circ}C$	-	18.0	-	А
Q _{rr}	Diode Reverse Recovery Charge	Ť	-	1800	-	nC

Electrical Characteristics of the DIODE $T_{C} = 25^{\circ}C$ unless otherwise noted

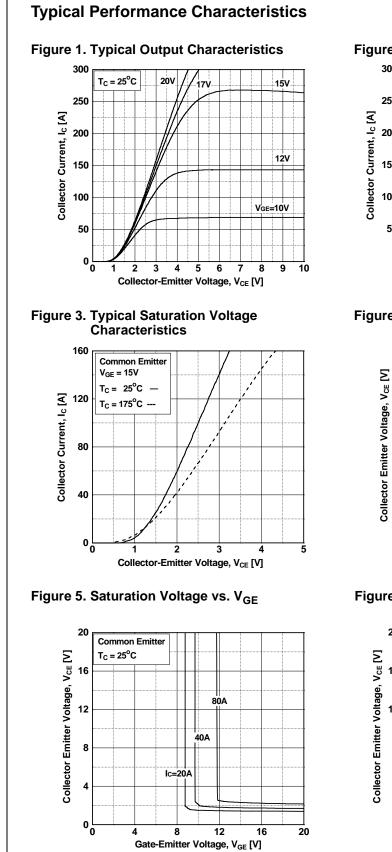
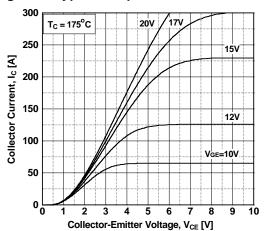
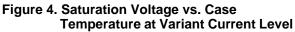


Figure 2. Typical Output Characteristics





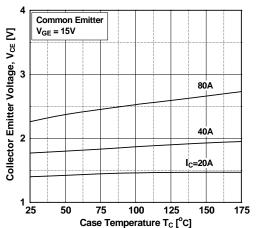
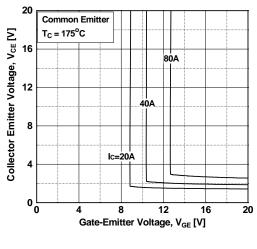


Figure 6. Saturation Voltage vs. V_{GE}



T_C = 100°C

100k

40

50

60

t_{d(on)}

Common Emitter

= 25°C ____

= 175°C -Tc

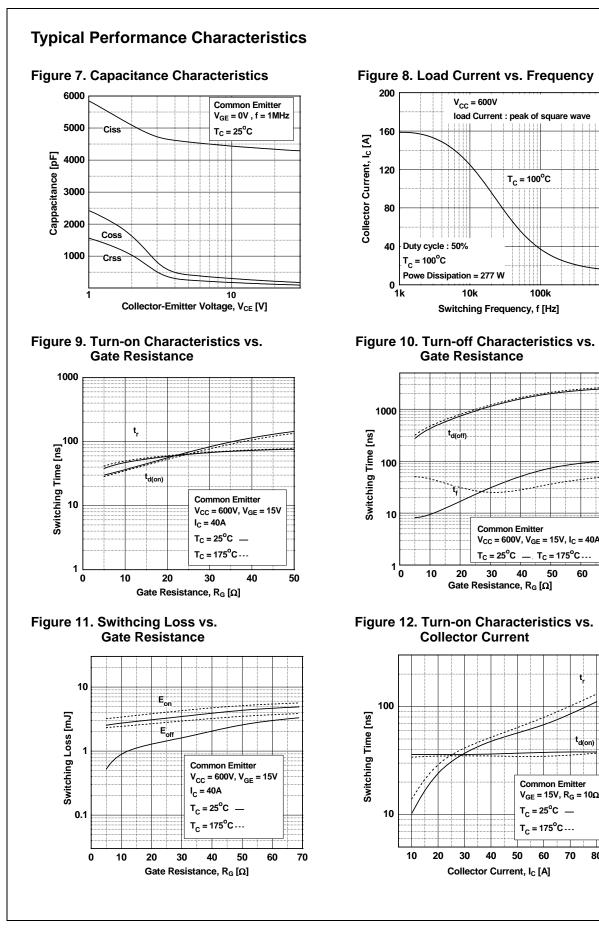
60

50

 $V_{GE} = 15V, R_G = 10\Omega$

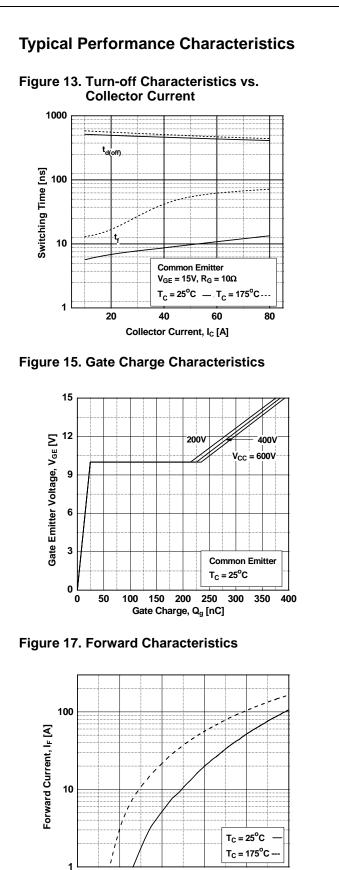
70 80 70

1M



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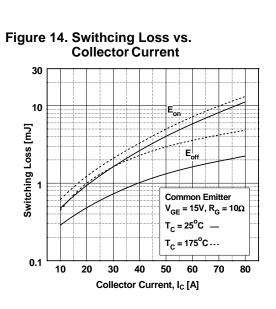


Figure 16. SOA Characteristics

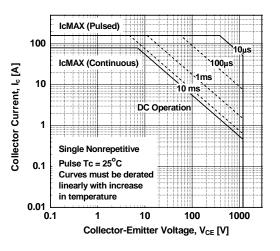
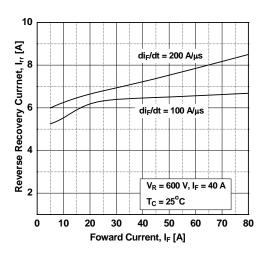


Figure 18. Reverse Recovery Current



1

0

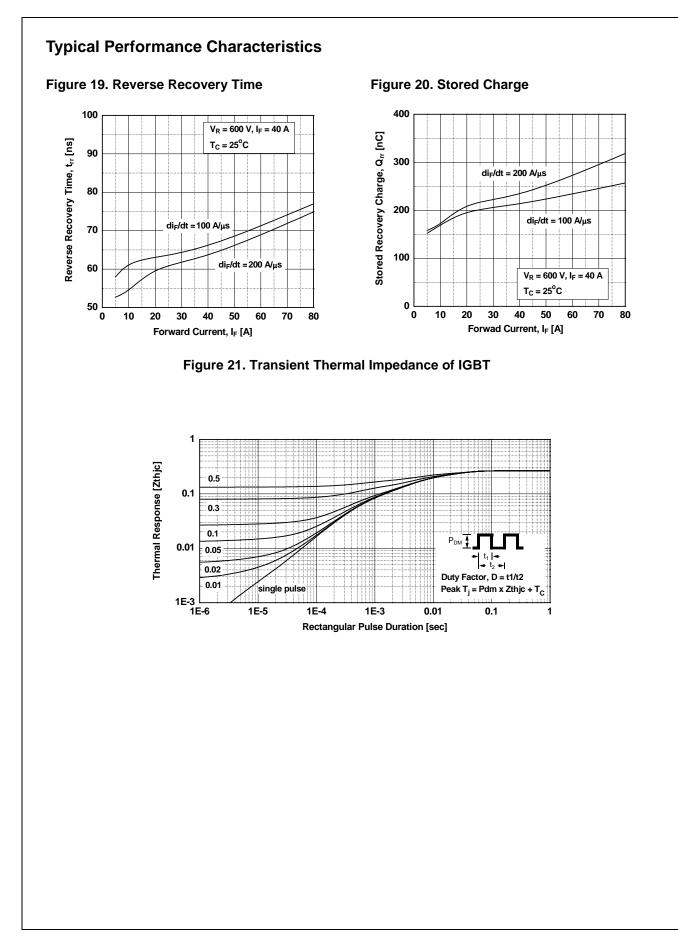
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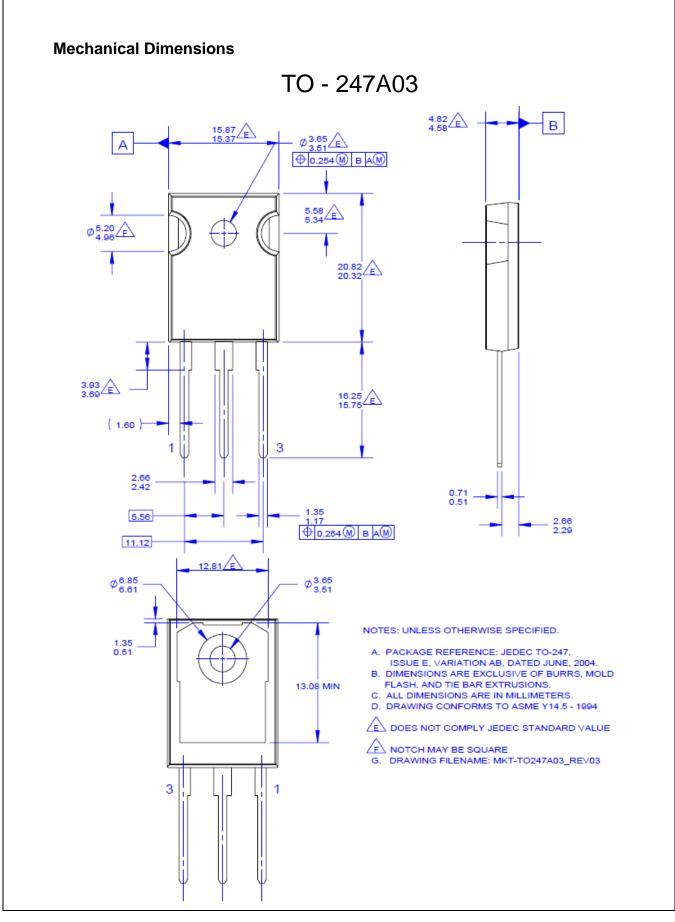
Forward Voltage, V_F [V]

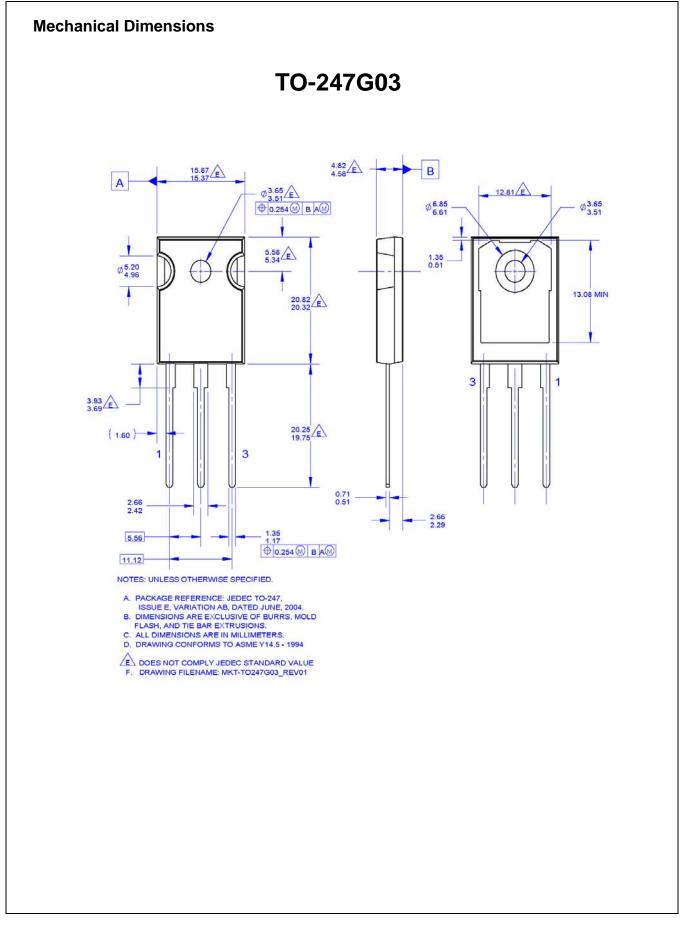
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